

# DATA SHEET

## **UAA2082** Advanced pager receiver

Product specification  
Supersedes data of 1996 Jan 15  
File under Integrated Circuits, IC03

2000 Nov 15

# Advanced pager receiver

# UAA2082

## FEATURES

- Wide frequency range: VHF, UHF and 900 MHz bands
- High sensitivity
- High dynamic range
- Electronically adjustable filters on chip
- Suitable for data rates up to 2400 bits/s
- Wide frequency offset and deviation range
- Fully POCSAG compatible FSK receiver
- Power on/off mode selectable by the chip enable input
- Low supply voltage; low power consumption
- 1-cell battery-low detection circuit
- High integration level
- Interfaces directly to the PCA5000A, PCF5001 and PCD5003 POCSAG decoders.

## APPLICATIONS

- Wide area paging
- On-site paging
- Telemetry
- RF security systems
- Low bit-rate wireless data links.

## GENERAL DESCRIPTION

The UAA2082 is a high-performance low-power radio receiver circuit primarily intended for VHF, UHF and 900 MHz pager receivers for wide area digital paging systems, employing direct FM non-return-to-zero (NRZ) frequency shift keying (FSK).

The receiver design is based on the direct conversion principle where the input signal is mixed directly down to the baseband by a local oscillator on the signal frequency. Two complete signal paths with signals of 90° phase difference are required to demodulate the signal. All channel selectivity is provided by the built-in IF filters. The circuit makes extensive use of on-chip capacitors to minimize the number of external components.

The battery monitoring circuit has an external sense input and a 1.1 V detection threshold for easy operation in a single-cell supply concept.

The UAA2082 is designed to operate together with the PCA5000A, PCF5001 or PCD5003 POCSAG decoders, which contain a digital input filter for optimum call success rate.

## ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	Description	VERSION
UAA2082H	LQFP32	plastic low profile quad flat package; 32 leads; body 7 × 7 × 1.4 mm	SOT358-1
UAA2082U	28 pads	naked die; see Fig.7	

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## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_P$	supply voltage		1.9	2.05	3.5	V
$I_P$	supply current		2.3	2.7	3.2	mA
$I_{P(off)}$	stand-by current		–	–	3	$\mu$ A
$P_{i(ref)}$	RF input sensitivity	BER $\leq 3/100$ ; $\pm 4$ kHz deviation; data rate 1200 bits/s; $T_{amb} = 25$ °C $f_{i(RF)} = 173$ MHz	–	–126.5	–123.5	dBm
		$f_{i(RF)} = 470$ MHz	–	–124.5	–121.5	dBm
$P_{i(mix)}$	mixer input sensitivity	BER $\leq 3/100$ ; $f_{i(RF)} = 470$ MHz; $\pm 4$ kHz deviation; data rate 1200 bits/s; $T_{amb} = 25$ °C	–	–115.0	–110.0	dBm
$V_{th}$	detection threshold for battery LOW indicator	$T_{amb} = 25$ °C	1.05	1.10	1.15	V
		$T_{amb} = -10$ to $+70$ °C	1.03	1.10	1.17	V
$T_{amb}$	operating ambient temperature		–10	–	+70	°C

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## BLOCK DIAGRAMS (173 MHz)

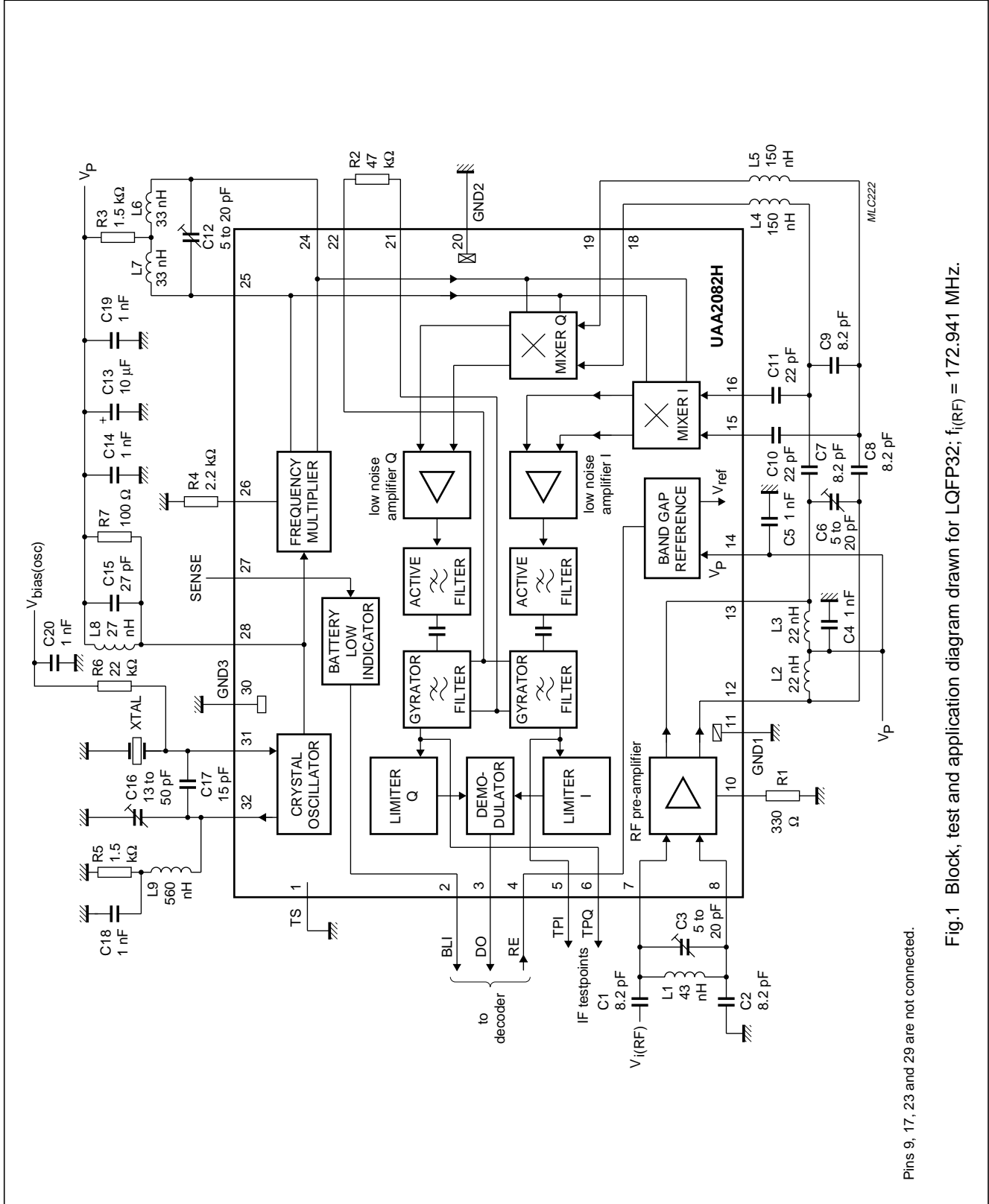


Fig.1 Block, test and application diagram drawn for LQFP32;  $f_{i(RF)} = 172.941$  MHz.

Plns 9, 17, 23 and 29 are not connected.

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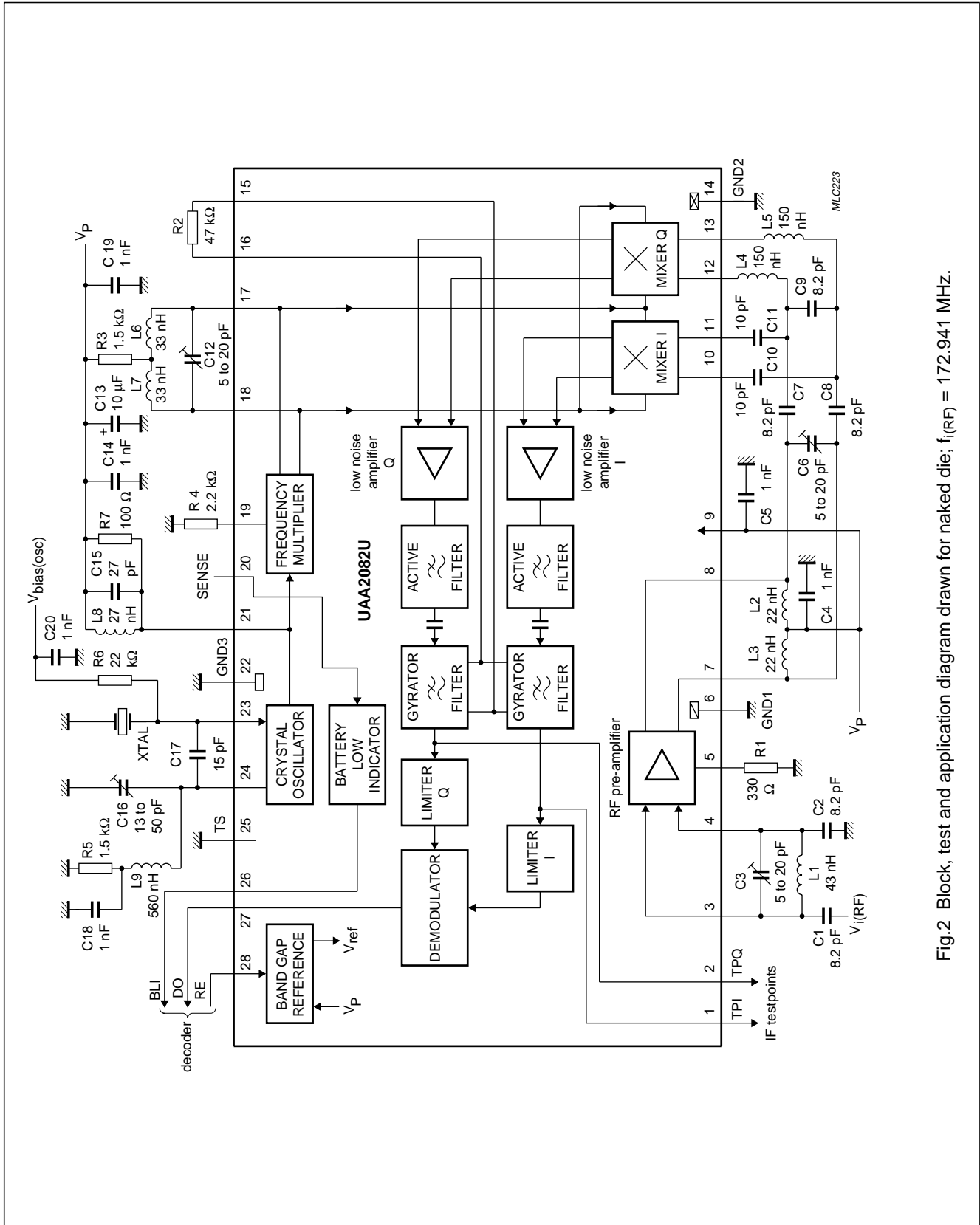


Fig.2 Block, test and application diagram drawn for naked die;  $f_{i(RF)} = 172.941$  MHz.

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**Table 1** Tolerances of components shown in Figs 1 and 2 (notes 1 and 2)

COMPONENT	TOLERANCE (%)	REMARK
<b>Inductances</b>		
L1	±5	$Q_{\min} = 100$ at 173 MHz
L2, L3, L6, L7	±20	$Q_{\min} = 50$ at 173 MHz; TC = $(+25 \text{ to } +125) \times 10^{-6}/\text{K}$
L4, L5	±10	$Q_{\min} = 30$ at 173 MHz; TC = $(+25 \text{ to } +125) \times 10^{-6}/\text{K}$
L8	±20	$Q_{\min} = 30$ at 173 MHz; TC = $(+25 \text{ to } +125) \times 10^{-6}/\text{K}$
L9	±10	$Q_{\min} = 30$ at 57 MHz; TC = $(+25 \text{ to } +125) \times 10^{-6}/\text{K}$
<b>Resistors</b>		
R1 to R7	±2	TC = $+50 \times 10^{-6}/\text{K}$
<b>Capacitors</b>		
C1, C2, C7, C8, C9, C15	±5	TC = $(0 \pm 30) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 30 \times 10^{-4}$ at 1 MHz
C3, C6, C12	–	TC = $(-750 \pm 300) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 50 \times 10^{-4}$ at 1 MHz
C4, C5, C14, C18, C19, C20	±10	TC = $(0 \pm 30) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 10 \times 10^{-4}$ at 1 MHz
C10, C11	±5	TC = $(0 \pm 30) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 21 \times 10^{-4}$ at 1 MHz
C13	±20	
C16	–	TC = $(-1700 \pm 500) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 50 \times 10^{-4}$ at 1 MHz
C17	±5	TC = $(0 \pm 30) \times 10^{-6}/\text{K}$ ; $\tan \delta \leq 26 \times 10^{-4}$ at 1 MHz

**Notes**

1. Recommended crystal:  $f_{\text{XTAL}} = 57.647$  MHz (crystal with 8 pF load), 3rd overtone, pullability  $>2.75 \times 10^{-6}/\text{pF}$  (change in frequency between series resonance and resonance with 8 pF series capacitor at 25 °C), dynamic resistance  $R1 < 40 \Omega$ ,  $\Delta f = \pm 5 \times 10^{-6}$  for  $T_{\text{amb}} = -10$  to  $+55$  °C with 25 °C reference, calibration plus aging tolerance:  $-5 \times 10^{-6}$  to  $+15 \times 10^{-6}$ .
2. This crystal recommendation is based on economic aspects and practical experience. Normally the spreads for R1, pullability and calibration do not show their worst case limits simultaneously in one crystal. In such a rare event, the tuning range will be reduced to an insufficient level.

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BLOCK AND TEST DIAGRAMS (470 MHz)

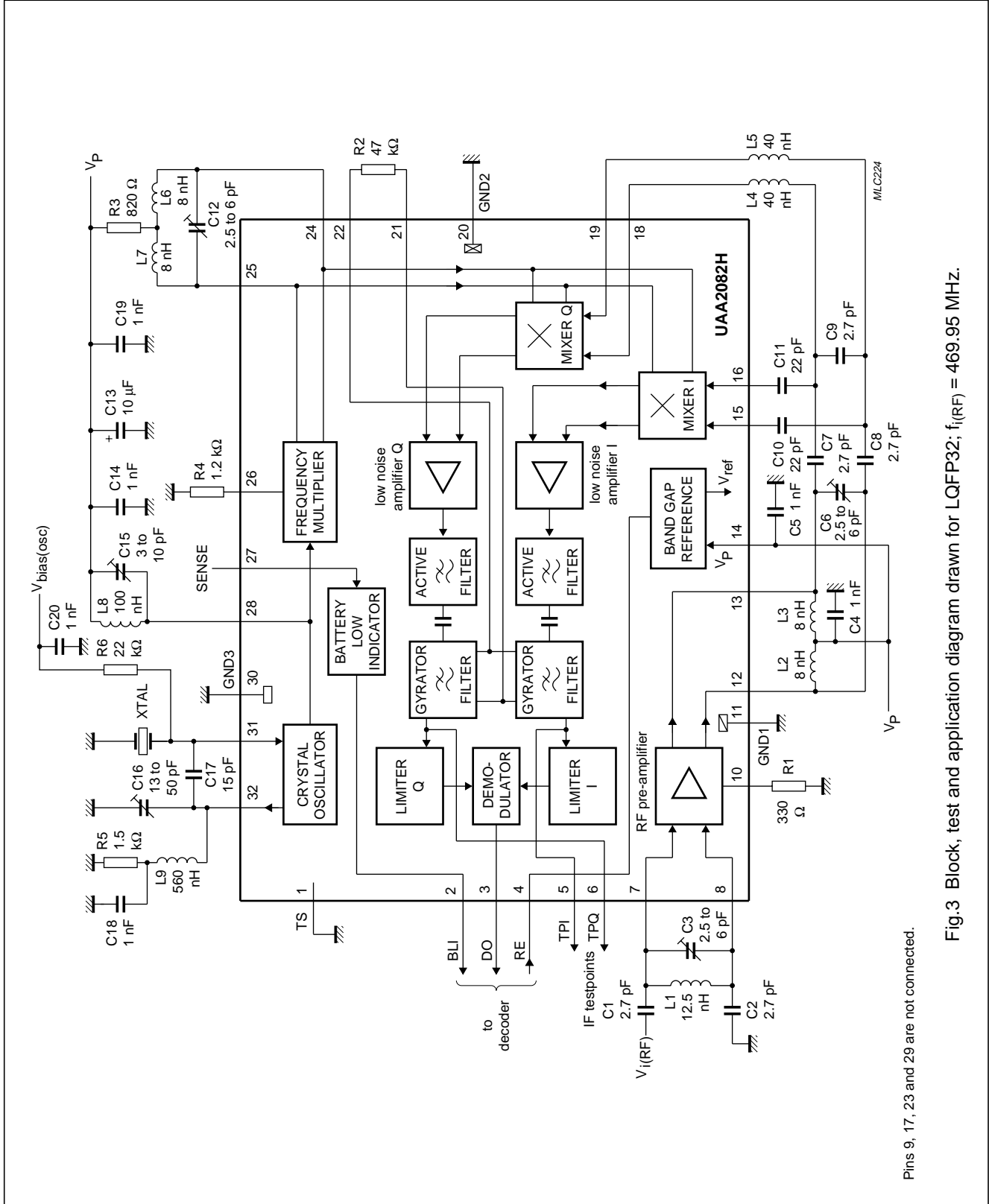


Fig.3 Block, test and application diagram drawn for LQFP32;  $f_i(\text{RF}) = 469.95 \text{ MHz}$ .

Pins 9, 17, 23 and 29 are not connected.

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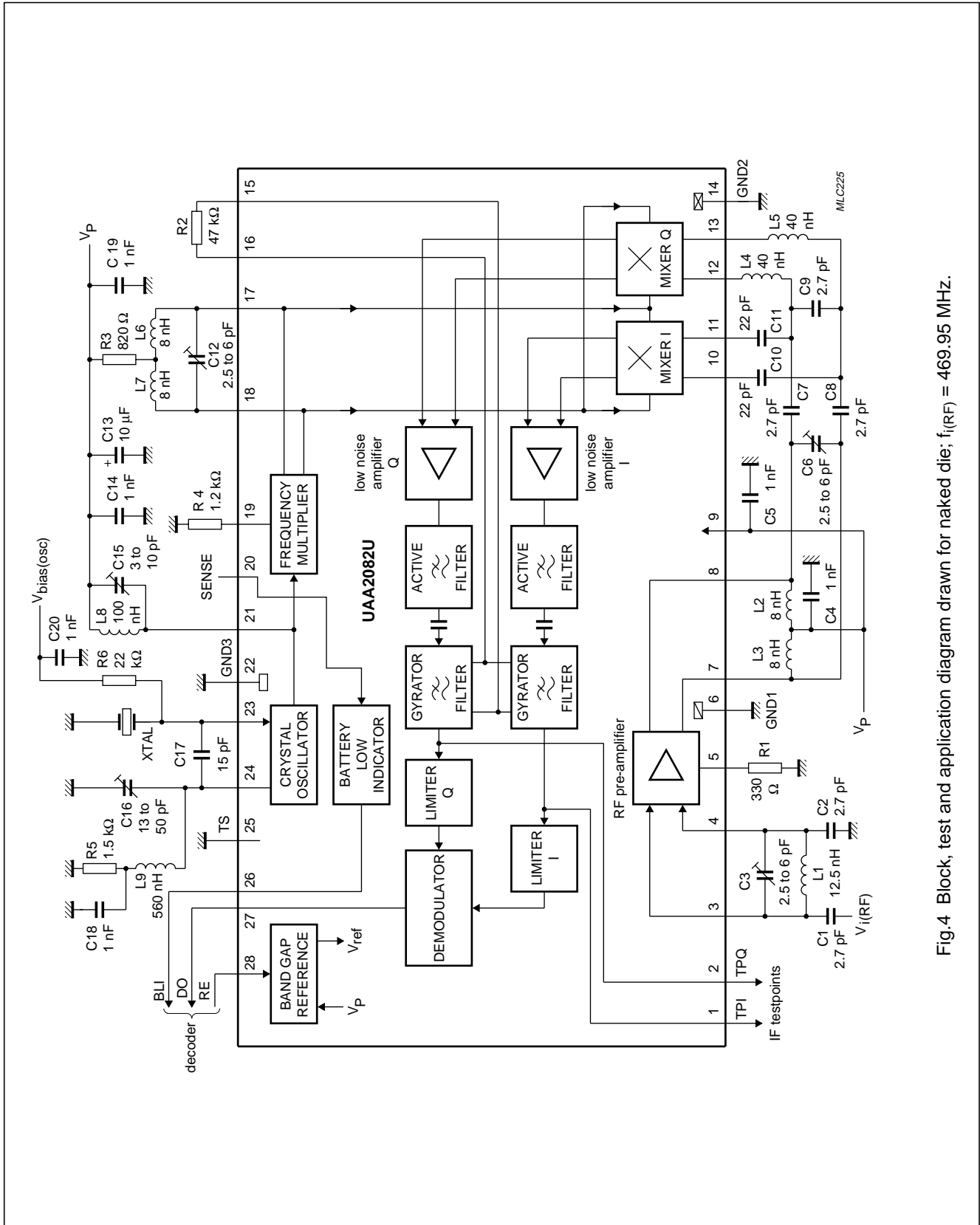


Fig.4 Block, test and application diagram drawn for naked die;  $f_{i(RF)} = 469.95 \text{ MHz}$ .



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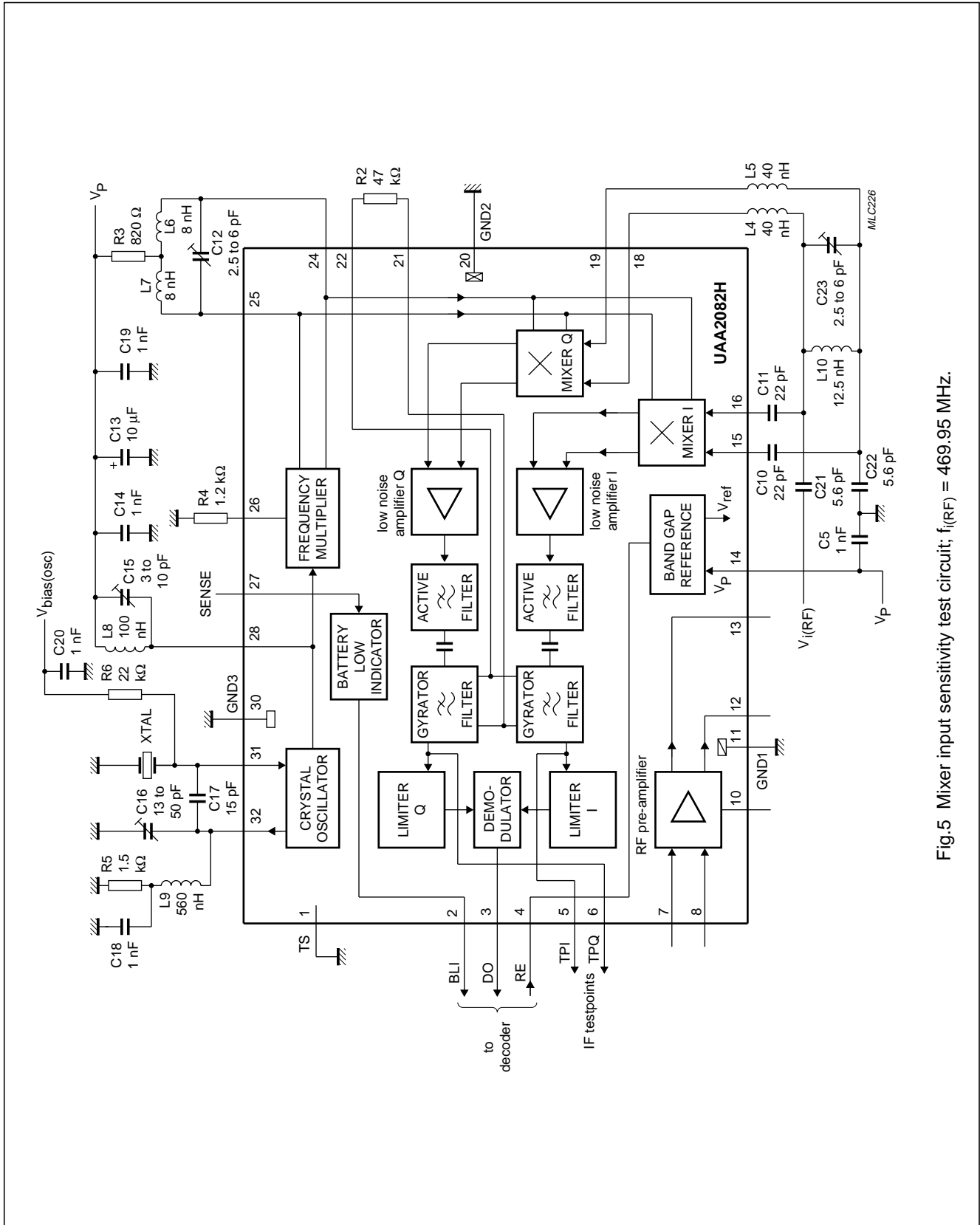


Fig.5 Mixer input sensitivity test circuit;  $f_{i(RF)} = 469.95$  MHz.

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**Table 2** Tolerances of components shown in Figs 3, 4 and 5 (notes 1 and 2)

COMPONENT	TOLERANCE (%)	REMARK
<b>Inductances</b>		
L1, L10	±5	$Q_{\min} = 145$ at 470 MHz
L2, L3, L6, L7	±20	$Q_{\min} = 50$ at 470 MHz; $TC = (+25 \text{ to } +125) \times 10^{-6}/K$
L4, L5	±10	$Q_{\min} = 40$ at 470 MHz; $TC = (+25 \text{ to } +125) \times 10^{-6}/K$
L8	±10	$Q_{\min} = 30$ at 156 MHz; $TC = (+25 \text{ to } +125) \times 10^{-6}/K$
L9	±10	$Q_{\min} = 40$ at 78 MHz; $TC = (+25 \text{ to } +125) \times 10^{-6}/K$
<b>Resistors</b>		
R1 to R6	±2	$TC = +50 \times 10^{-6}/K$
<b>Capacitors</b>		
C1, C2, C7, C8, C9	±5	$TC = (0 \pm 30) \times 10^{-6}/K$ ; $\tan \delta \leq 30 \times 10^{-4}$ at 1 MHz
C3, C6, C12, C23	–	$TC = (-750 \pm 300) \times 10^{-6}/K$ ; $\tan \delta \leq 50 \times 10^{-4}$ at 1 MHz
C4, C5, C14, C18 to C22	±10	$TC = (0 \pm 30) \times 10^{-6}/K$ ; $\tan \delta \leq 10 \times 10^{-4}$ at 1 MHz
C10, C11	±5	$TC = (0 \pm 30) \times 10^{-6}/K$ ; $\tan \delta \leq 21 \times 10^{-4}$ at 1 MHz
C13	±20	
C16	–	$TC = (-1700 \pm 500) \times 10^{-6}/K$ ; $\tan \delta \leq 50 \times 10^{-4}$ at 1 MHz
C17	±5	$TC = (0 \pm 30) \times 10^{-6}/K$ ; $\tan \delta \leq 26 \times 10^{-4}$ at 1 MHz

**Notes**

- Recommended crystal:  $f_{XTAL} = 78.325$  MHz (crystal with 8 pF load), 3rd overtone, pullability  $>2.75 \times 10^{-6}/pF$  (change in frequency between series resonance and resonance with 8 pF capacitor at 25 °C), dynamic resistance  $R1 < 30 \Omega$ ,  $\Delta f = \pm 5 \times 10^{-6}$  for  $T_{amb} = -10$  to  $+55$  °C with 25 °C reference, calibration plus aging tolerance:  $-5 \times 10^{-6}$  to  $+15 \times 10^{-6}$ .
- This crystal recommendation is based on economic aspects and practical experience. Normally the spreads for R1, pullability and calibration do not show their worst case limits simultaneously in one crystal. In such a rare event, the tuning range will be reduced to an insufficient level.

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### PINNING (LQFP32)

SYMBOL	PIN	DESCRIPTION
TS	1	test switch; connection to ground for normal operation
BLI	2	battery LOW indicator output
DO	3	data output
RE	4	receiver enable input
TPI	5	IF test point; I channel
TPQ	6	IF test point; Q channel
VI1RF	7	pre-amplifier RF input 1
VI2RF	8	pre-amplifier RF input 2
n.c.	9	not connected
RRFA	10	external emitter resistor for pre-amplifier
GND1	11	ground 1 (0 V)
VO2RF	12	pre-amplifier RF output 2
VO1RF	13	pre-amplifier RF output 1
V <sub>P</sub>	14	supply voltage
VI2MI	15	I channel mixer input 2
VI1MI	16	I channel mixer input 1
n.c.	17	not connected
VI1MQ	18	Q channel mixer input 1
VI2MQ	19	Q channel mixer input 2
GND2	20	ground 2 (0 V)
COM	21	gyrator filter resistor; common line
RGYR	22	gyrator filter resistor
n.c.	23	not connected
VO1MUL	24	frequency multiplier output 1
VO2MUL	25	frequency multiplier output 2
RMUL	26	external emitter resistor for frequency multiplier
SENSE	27	battery LOW detector sense input
OSC	28	oscillator collector
n.c.	29	not connected
GND3	30	ground 3 (0 V)
OSB	31	oscillator base; crystal input
OSE	32	oscillator emitter

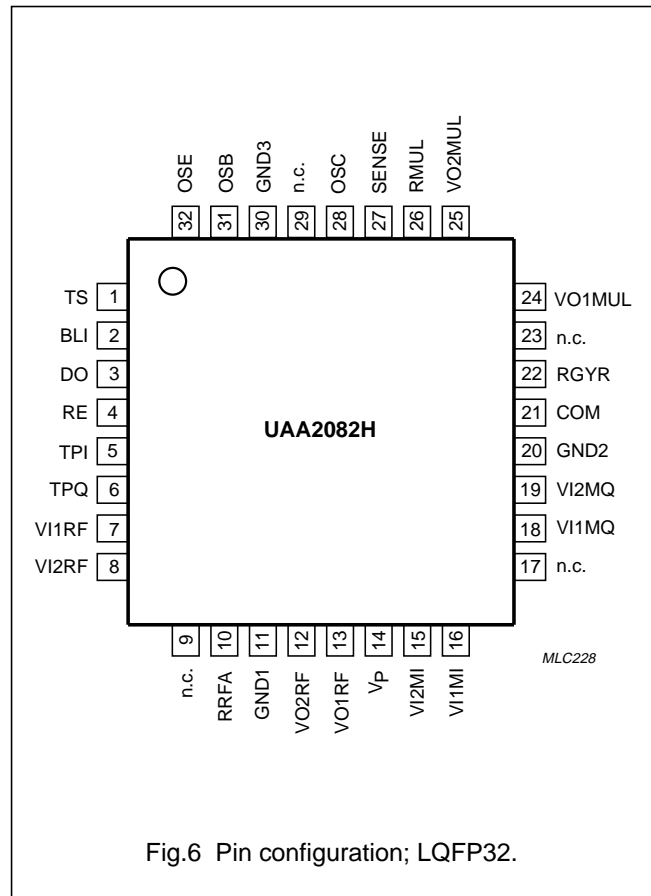


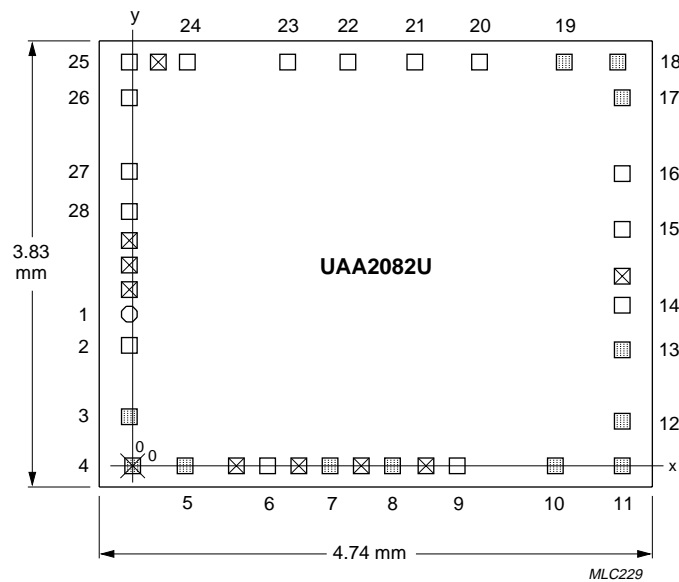
Fig.6 Pin configuration; LQFP32.

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CHIP DIMENSIONS AND BONDING PAD LOCATIONS

See Table 3 for bonding pad description and locations for x/y co-ordinates.



Where:

- Pad number 1 (diameter 124 μm)
- Pad 124 μm x 124 μm
- ⊗ Pad not used
- ▣ Pad 100 μm x 100 μm
- ⊠ Pad 100 μm x 100 μm with reference point

Chip area: 18.15 mm<sup>2</sup>  
 Chip thickness: 380 ±20 μm.  
 Drawing not to scale.

Fig.7 Bonding pad locations.

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**Table 3** Bonding pad centre locations (dimensions in  $\mu\text{m}$ )

SYMBOL	PAD	DESCRIPTION	X	Y
TPI	1	IF test point; I channel	-32	1296
TPQ	2	IF test point; Q channel	-32	1000
VI1RF	3	pre-amplifier RF input 1	-32	360
VI2RF	4	pre-amplifier RF input 2; note 1	0	0
RRFA	5	external emitter resistor for pre-amplifier	472	0
GND1	6	ground 1 (0 V)	1160	0
VO2RF	7	pre-amplifier RF output 2	1688	0
VO1RF	8	pre-amplifier RF output 1	2232	0
V <sub>P</sub>	9	supply voltage	2760	0
VI2MI	10	I channel mixer input 2	3608	0
VI1MI	11	I channel mixer input 1	4216	0
VI1MQ	12	Q channel mixer input 1	4216	360
VI2MQ	13	Q channel mixer input 2	4216	960
GND2	14	ground 2 (0 V)	4216	1360
COM	15	gyrator filter resistor; common line	4216	2024
RGYR	16	gyrator filter resistor	4216	2496
VO1MUL	17	frequency multiplier output 1	4216	3136
VO2MUL	18	frequency multiplier output 2	4176	3456
RMUL	19	external emitter resistor for frequency multiplier	3668	3458
SENSE	20	battery LOW detector sense input	2952	3456
OSC	21	oscillator collector	2312	3456
GND3	22	ground 3 (0 V)	1832	3456
OSB	23	oscillator base; crystal input	1328	3456
OSE	24	oscillator emitter	432	3456
TS	25	test switch; connection to ground for normal operation	-32	3456
BLI	26	battery LOW indicator output	-32	3136
DO	27	data output	-32	2512
RE	28	receiver enable input	-32	2152
		lower left corner of chip (typical values)	-278	-186

**Note**

1. All x/y co-ordinates are referenced to the centre of pad 4 (VI2RF); see Fig.7.

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## INTERNAL CIRCUITS

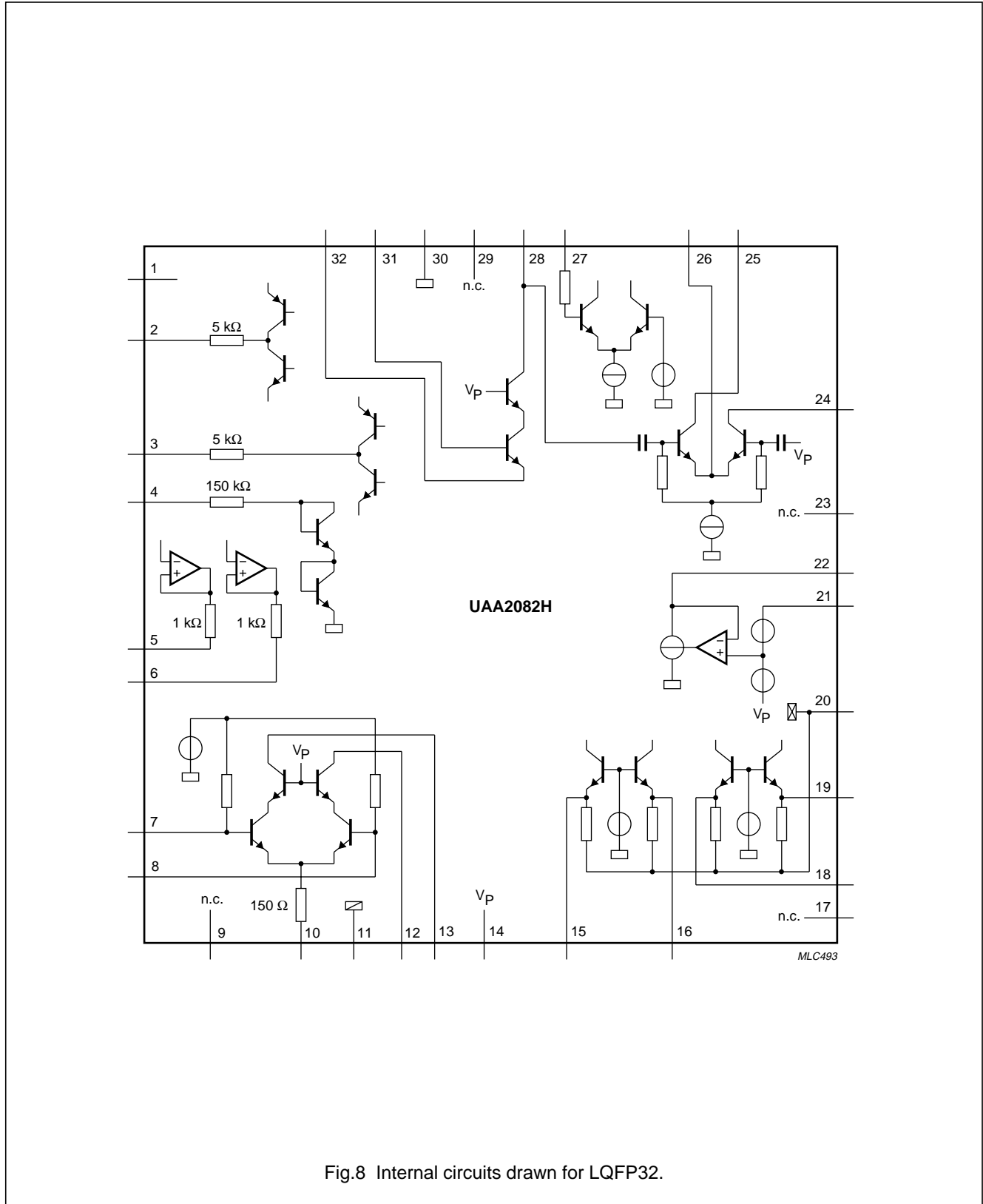


Fig.8 Internal circuits drawn for LQFP32.

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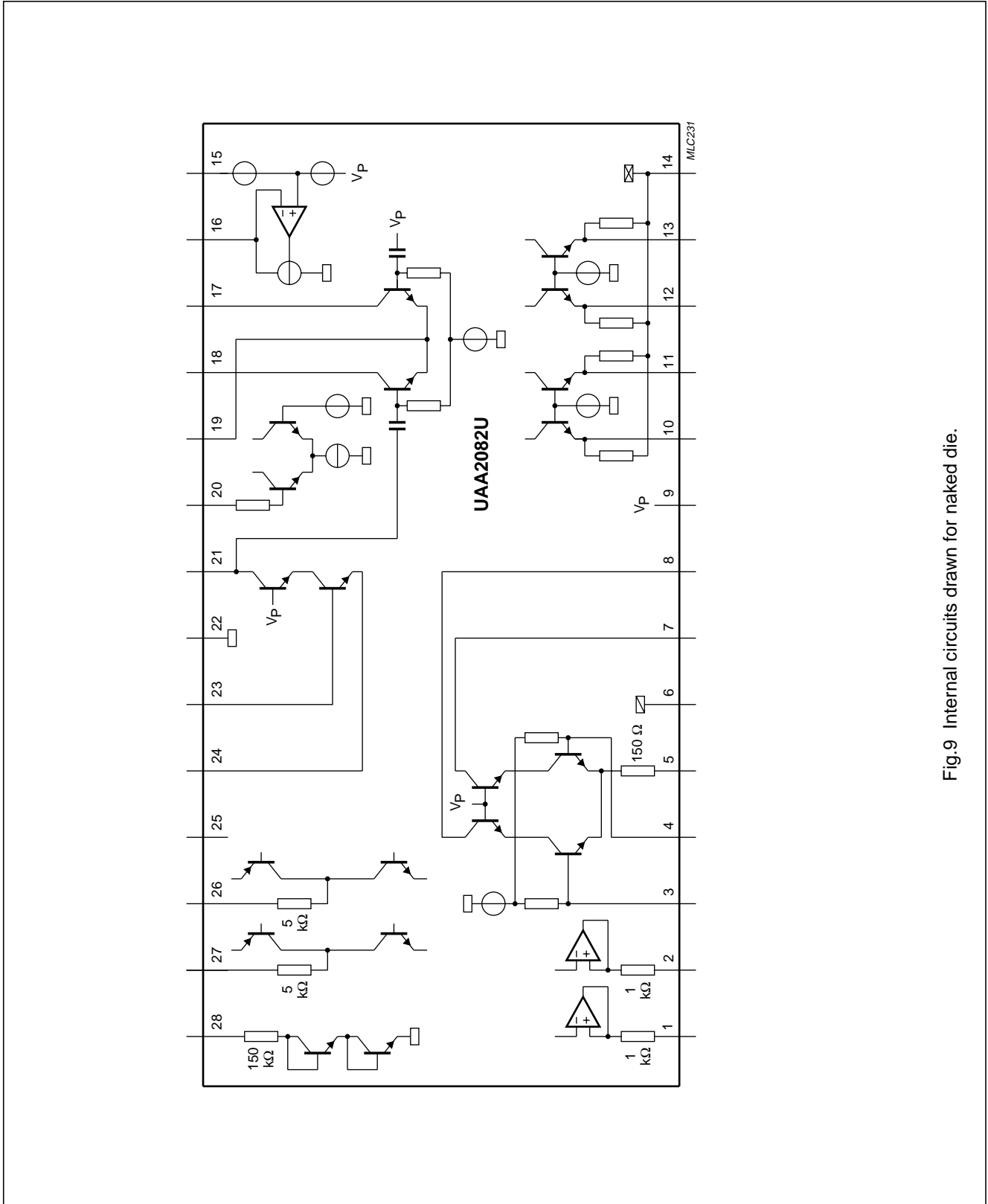


Fig.9 Internal circuits drawn for naked die.

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### FUNCTIONAL DESCRIPTION

The complete circuit consists of the following functional blocks as shown in Figs 1 to 5.

#### Radio frequency amplifier

The RF amplifier is an emitter-coupled pair driving a balanced cascode stage, which drives an external balanced tuned circuit. Its bias current is set by an external 300  $\Omega$  resistor R1 to typically 770  $\mu$ A. With this bias current, the optimum source resistance is 1.3 k $\Omega$  at VHF and 1.0 k $\Omega$  at UHF.

If a value of 120  $\Omega$  is used for R1, this corresponds with a bias current of approximately 1.3 mA and an optimum source resistance of approximately 600  $\Omega$ . Capacitors C1 and C2 transform a 50  $\Omega$  source resistance to this optimum value. The output drives a tuned circuit with capacitive divider (C7, C8 and C9) to provide maximum power transfer to the phase-splitting network and the mixers.

#### Mixers

The double balanced mixers consist of common base input stages and upper switching stages driven from the frequency multiplier. The 300  $\Omega$  input impedance of each mixer acts together with external components (C10, C11; L4, L5 respectively) as phase shifter/power splitter to provide a differential phase shift of 90 degrees between the I channel and the Q channel.

#### Oscillator

The oscillator is based on a transistor in common collector configuration. It is followed by a cascode stage driving a tuned circuit which provides the signal for the frequency multiplier. The oscillator transistor requires an external bias voltage  $V_{\text{bias(osc)}}$  (1.22 V typ.). The oscillator bias current (typically 250  $\mu$ A) is determined by the 1.5 k $\Omega$  external resistor R5. The oscillator frequency is controlled by an external 3rd overtone crystal in parallel resonance mode. External capacitors between base and emitter (C17) and from emitter to ground (C16) make the oscillator transistor appear as having a negative resistance for small signals; this causes the oscillator to start. Inductance L9 connected in parallel with capacitor C16 to the emitter of the oscillator transistor prevents oscillation at the fundamental frequency of the crystal.

The resonant circuit at output pin OSC selects the second harmonic of the oscillator frequency. In other applications a different multiplication factor may be chosen.

#### Frequency multiplier

The frequency multiplier is an emitter-coupled pair driving an external balanced tuned circuit. Its bias current is set by external resistor R4 to typically 190  $\mu$ A (173 MHz) and 350  $\mu$ A (470 MHz). The oscillator signal is internally AC coupled to one input of the emitter-coupled pair while the other input is internally grounded via a capacitor. The frequency multiplier output signal between pins VO1MUL and VO2MUL drives the upper switching stages of the mixers. The bias voltage on pins VO1MUL and VO2MUL is set by external resistor R3 to allow sufficient voltage swing at the mixer outputs. The value of R3 depends on the operating frequency: 1.5 k $\Omega$  (173 MHz) and 820  $\Omega$  (470 MHz).

#### Low noise amplifiers, active filters and gyrator filters

The low noise amplifiers ensure that the noise of the following stages does not affect the overall noise figure. The following active filters before the gyrator filters reduce the levels of large signals from adjacent channels. Internal AC couplings block DC offsets from the gyrator filter inputs.

The gyrator filters implement the transfer function of a 7th order elliptic filter. Their cut-off frequencies are determined by the 47 k $\Omega$  external resistor R2 between pins RGYR and COM. The gyrator filter output signals are available on IF test pins TPI and TPQ.

#### Limiters

The gyrator filter output signals are amplified in the limiter amplifiers to obtain IF signals with removed amplitude information.

#### Demodulator

The limiter amplifier output signals are fed to the demodulator. Demodulator output DO goes LOW or HIGH, depending on which of the input signals has a phase lead.

#### Battery LOW indicator

The battery LOW indicator senses the supply voltage and sets its output HIGH when the voltage at input SENSE is less than  $V_{\text{th}}$  (typically 1.10 V). Low battery warning is available at BLI.

#### Band gap reference

The whole chip except the oscillator section can be powered-up and powered-down by enabling and disabling the band gap reference via the receiver enable pin RE.



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**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Ground pins GND1, GND2 and GND3 are connected together.

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
$V_P$	supply voltage	-0.3	+8.0	V
$T_{stg}$	storage temperature	-55	+125	°C
$T_{amb}$	operating ambient temperature	-10	+70	°C
$V_{es}$	electrostatic handling; note 1			
	pins VI1RF and VI2RF	-1500	+2000	V
	pin RRFA	-500	+2000	V
	pins VO1RF and VO2RF	-2000	+250	V
	pins $V_P$ and OSB	-500	+500	V
	pins OSC and OSE	-2000	+500	V
	other pins	-2000	+2000	V

**Note**

- Equivalent to discharging a 100 pF capacitor via a 1.5 kΩ resistor.

**DC CHARACTERISTICS**

$V_P = 2.05$  V;  $T_{amb} = -10$  to  $+70$  °C (typical values at  $T_{amb} = 25$  °C); measurements taken in test circuit Figs 1, 2, 3 or 4 with crystal at pin OSB disconnected; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>Supply</b>						
$V_P$	supply voltage		1.9	2.05	3.5	V
$I_P$	supply current	$V_{RE} = \text{HIGH}$ ; $f_{i(RF)} = 173$ and 470 MHz	2.3	2.7	3.2	mA
$I_{P(off)}$	stand-by current	$V_{RE} = \text{LOW}$	–	–	3	μA
$V_{bias(osc)}$	oscillator bias voltage		1.20	1.22	1.24	V
<b>Receiver enable input (pin RE)</b>						
$V_{IH}$	HIGH level input voltage		1.4	–	$V_P$	V
$V_{IL}$	LOW level input voltage		0	–	0.3	V
$I_{IH}$	HIGH level input current	$V_{IH} = V_P = 3.5$ V	–	–	20	μA
$V_{IL}$	LOW level input current	$V_{IL} = 0$ V	0	–	-1.0	μA
<b>Battery LOW indicator output (pin BLI)</b>						
$V_{OH}$	HIGH level output voltage	$V_{SENSE} < V_{th}$ ; $I_{BLI} = -10$ μA	$V_P - 0.5$	–	–	V
$V_{OL}$	LOW level output voltage	$V_{SENSE} > V_{th}$ ; $I_{BLI} = +10$ μA	–	–	0.5	V
$V_{th}$	voltage threshold for battery LOW indicator	$V_P = 2.05$ V; $T_{amb} = 25$ °C	1.05	1.10	1.15	V
		$V_P = 2.05$ to 3.5 V; $T_{amb} = -10$ to $+70$ °C	1.03	1.10	1.17	V
<b>Demodulator output (pin DO)</b>						
$V_{OH}$	HIGH level output voltage	$I_{DO} = -10$ μA	$V_P - 0.5$	–	–	V
$V_{OL}$	LOW level output voltage	$I_{DO} = +10$ μA	–	–	0.5	V

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**AC CHARACTERISTICS (173 MHz)**

$V_P = 2.05$  V;  $T_{amb} = 25$  °C; test circuit Figs 1 or 2;  $f_{i(RF)} = 172.941$  MHz with  $\pm 4.0$  kHz deviation; 1200 baud pseudo random bit sequence modulation ( $t_r = 250 \pm 25$   $\mu$ s measured between 10% and 90% of voltage amplitude) and 20 kHz channel spacing; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>Radio frequency input</b>						
$P_{i(ref)}$	input sensitivity ( $P_{i(ref)}$ is the maximum available power at the RF input of the test board)	$BER \leq \frac{3}{100}$ ; note 1	–	–126.5	–123.5	dBm
		$T_{amb} = -10$ to $+70$ °C; note 2	–	–	–120.5	dBm
		$V_P = 1.9$ V	–	–	–117.5	dBm
<b>Mixers to demodulator</b>						
$\alpha_{acs}$	adjacent channel selectivity	$T_{amb} = 25$ °C	69	72	–	dB
		$T_{amb} = -10$ to $+70$ °C	67	–	–	dB
$\alpha_{ci}$	IF filter channel imbalance		–	–	2	dB
$\alpha_c$	co-channel rejection		–	4	7	dB
$\alpha_{sp}$	spurious immunity		50	60	–	dB
$\alpha_{im}$	intermodulation immunity		55	60	–	dB
$\alpha_{bl}$	blocking immunity	$\Delta f > \pm 1$ MHz; note 3	78	85	–	dB
$f_{offset}$	frequency offset range (3 dB degradation in sensitivity)	deviation $f = \pm 4.0$ kHz	$\pm 2.0$	–	–	kHz
		deviation $f = \pm 4.5$ kHz	$\pm 2.5$	–	–	kHz
$\Delta f_{dev}$	deviation range (3 dB degradation in sensitivity)		2.5	–	7.0	kHz
$t_{on}$	receiver turn-on time	data valid after setting RE input HIGH; note 4	–	–	5	ms

**Notes**

1. The bit error rate BER is measured using the test facility shown in Fig.11. Note that the BER test facility contains a digital input filter equivalent to the one used in the PCA5000A, PCF5001 and PCD5003 POCSAG decoders.
2. Capacitor C16 requires re-adjustment to compensate temperature drift.
3.  $\Delta f$  is the frequency offset between the required signal and the interfering signal.
4. Turn-on time is defined as the time from pin RE going HIGH to the reception of valid data on output pin DO. Turn-on time is measured using an external oscillator (turn-on time using the internal oscillator depends on the oscillator circuit).

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**AC CHARACTERISTICS (470 MHz)**

$V_P = 2.05$  V;  $T_{amb} = 25$  °C; test circuit Figs 3 or 4;  $f_{i(RF)} = 469.950$  MHz with  $\pm 4.0$  kHz deviation; 1200 baud pseudo random bit sequence modulation ( $t_r = 250 \pm 25$   $\mu$ s measured between 10% and 90% of voltage amplitude) and 20 kHz channel spacing; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>Radio frequency input</b>						
$P_{i(ref)}$	input sensitivity ( $P_{i(ref)}$ is the maximum available power at the RF input of the test board)	$BER \leq \frac{3}{100}$ ; note 1	–	–124.5	–121.5	dBm
		$T_{amb} = -10$ to $+70$ °C; note 2	–	–	–118.5	dBm
		$V_P = 1.9$ V	–	–	–115.5	dBm
<b>Mixer input</b>						
$P_{i(mix)}$	input sensitivity	$BER \leq \frac{3}{100}$ ; note 3	–	–115.0	–110.0	dBm
<b>Mixers to demodulator</b>						
$\alpha_{acs}$	adjacent channel selectivity	$T_{amb} = 25$ °C	67	70	–	dB
		$T_{amb} = -10$ to $+70$ °C	65	–	–	dB
$\alpha_{ci}$	IF filter channel imbalance		–	–	2	dB
$\alpha_c$	co-channel rejection		–	4	7	dB
$\alpha_{sp}$	spurious immunity		50	60	–	dB
$\alpha_{im}$	intermodulation immunity		55	60	–	dB
$\alpha_{bl}$	blocking immunity	$\Delta f > \pm 1$ MHz; note 4	75	82	–	dB
$f_{offset}$	frequency offset range (3 dB degradation in sensitivity)	deviation $f = \pm 4.0$ kHz	$\pm 2.0$	–	–	kHz
		deviation $f = \pm 4.5$ kHz	$\pm 2.5$	–	–	kHz
$\Delta f_{dev}$	deviation range (3 dB degradation in sensitivity)		2.5	–	7.0	kHz
$t_{on}$	receiver turn-on time	data valid after setting RE input HIGH; note 5	–	–	5	ms

**Notes**

- The bit error rate BER is measured using the test facility shown in Fig.11. Note that the BER test facility contains a digital input filter equivalent to the one used in the PCA5000A, PCF5001 and PCD5003 POCSAG decoders.
- Capacitor C16 requires re-adjustment to compensate temperature drift.
- Test circuit Fig.5.  $P_{i(mix)}$  is the maximum available power at the input of the test board. The bit error rate BER is measured using the test facility shown in Fig.11.
- $\Delta f$  is the frequency offset between the required signal and the interfering signal.
- Turn-on time is defined as the time from pin RE going HIGH to the reception of valid data on output pin DO. Turn-on time is measured using an external oscillator (turn-on time using the internal oscillator depends on the oscillator circuit).

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## TEST INFORMATION

## Tuning procedure for AC tests

1. Turn on the signal generator:  $f_{\text{gen}} = f_{i(\text{RF})} + 4 \text{ kHz}$ , no modulation,  $V_{i(\text{RF})} = 1 \text{ mV (RMS)}$ .
2. Measure the IF with a counter connected to test pin TPI. Tune C16 to set the crystal oscillator to achieve  $f_{i\text{F}} = 4 \text{ kHz}$ . Change the generator frequency to  $f_{\text{gen}} = f_{i(\text{RF})} - 4 \text{ kHz}$  and check that  $f_{i\text{F}}$  is also 4 kHz. For a received input frequency  $f_{i(\text{RF})} = 172.941 \text{ MHz}$ , the crystal frequency is  $f_{\text{XTAL}} = 57.647 \text{ MHz}$ , while for  $f_{i(\text{RF})} = 469.950 \text{ MHz}$ , the crystal frequency is  $f_{\text{XTAL}} = 78.325 \text{ MHz}$ .
3. Set the signal generator to nominal frequency ( $f_{i(\text{RF})}$ ) and turn on the modulation deviation  $\pm 4.0 \text{ kHz}$ , 600 Hz square wave modulation,  $V_{i(\text{RF})} = 1 \text{ mV (RMS)}$ . Note that the RF signal should be reduced in the following tests, as the receiver is tuned, to ensure  $V_{o(\text{IF})} = 10 \text{ to } 50 \text{ mV (p-p)}$  on test pins TPI or TPQ.
4. Tune C15 (oscillator output circuit) and C12 (frequency multiplier output) to obtain a peak audio voltage on pin TPI.
5. Tune C3 and C6 (RF input and mixer input) to obtain a peak audio voltage on pin TPI. When testing the mixer input sensitivity, tune C23 instead of C3 and C6 (test circuit Fig.5).
6. Check that the output signal on pin TPQ is within 3 dB in amplitude and at  $90^\circ (\pm 20^\circ)$  relative phase of the signal on pin TPI.
7. Check that data signal appears on output pin DO and proceed with the AC test.

## AC test conditions

Table 4 Definitions for AC test conditions (see Table 5)

SIGNAL	DESCRIPTION
<b>Modulated test signal 1</b>	
Frequency	172.941 or 469.950 MHz
Deviation	$\pm 4.0 \text{ kHz}$
Modulation	1200 baud pseudo random bit sequence
Rise time	$250 \pm 25 \mu\text{s}$ (between 10% and 90% of final value)
<b>Modulated test signal 2</b>	
Deviation	$\pm 2.4 \text{ kHz}$
Modulation	400 Hz sine wave
<b>Other definitions</b>	
$f_1$	frequency of signal generator 1
$f_2$	frequency of signal generator 2
$f_3$	frequency of signal generator 3
$\Delta f_{\text{cs}}$	channel spacing (20 kHz)
$P_1$	maximum available power from signal generator 1 at the test board input
$P_2$	maximum available power from signal generator 2 at the test board input
$P_3$	maximum available power from signal generator 3 at the test board input
$P_{i(\text{ref})}$	maximum available power at the test board input to give a Bit Error Rate (BER) $\leq \frac{3}{100}$ for the modulated test signal 1, in the absence of interfering signals and under the conditions as specified in Chapters "AC characteristics (173 MHz)" and "AC characteristics (470 MHz)".

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**Table 5** AC test conditions; notes 1 and 2

SYMBOL	PARAMETER	CONDITIONS	TEST SIGNALS
$\alpha_a$	adjacent channel selectivity; Fig.10(b)	$f_2 = f_1 \pm \Delta f_{CS}$ generator 1: modulated test signal 1 generator 2: modulated test signal 2	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$ $P_2 = P_1 + \alpha_{a(\text{min})}$
$\alpha_c$	co-channel rejection; Fig.10(b)	$f_2 = f_1 \pm$ up to 3 kHz generator 1: modulated test signal 1 generator 2: modulated test signal 2	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$ $P_2 = P_1 - \alpha_{c(\text{max})}$
$\alpha_{sp}$	spurious immunity; Fig.10(b)	$f_2 = 100 \text{ kHz to } 2 \text{ GHz}$ generator 1: modulated test signal 1 generator 2: modulated test signal 2	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$ $P_2 = P_1 + \alpha_{sp(\text{min})}$
$\alpha_{im}$	intermodulation immunity; Fig.10(c)	$f_2 = f_1 \pm \Delta f_{CS}; f_3 = f_1 \pm 2\Delta f_{CS}$ generator 1: modulated test signal 1 generator 2: unmodulated generator 3: modulated test signal 2	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$ $P_2 = P_1 + \alpha_{im(\text{min})}$ $P_3 = P_2$
$\alpha_{bl}$	blocking immunity; Fig.10(b)	$f_2 = f_1 \pm 1 \text{ MHz}$ generator 1: modulated test signal 1 generator 2: modulated test signal 2	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$ $P_2 = P_1 + \alpha_{bl(\text{min})}$
$f_{\text{offset}}$	frequency offset range; Fig.10(a)	deviation = $\pm 4.0 \text{ kHz}$ , $f_1 = f_{i(\text{RF})} \pm 2 \text{ kHz}$ ( $f_{\text{offset}(\text{min})}$ ) generator 1: modulated test signal 1	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$
$\Delta f_{\text{dev}}$	deviation range; Fig.10(a)	deviation = $\pm 2.5$ to $\pm 7 \text{ kHz}$ ; ( $\Delta f_{\text{dev}(\text{min})}$ to $\Delta f_{\text{dev}(\text{max})}$ ) generator 1: modulated test signal 1	$P_1 = P_{i(\text{ref})} + 3 \text{ dB}$
$t_{\text{on}}$	receiver turn-on time; Fig.10(a)	note 3 generator 1: modulated test signal 1	$P_1 = P_{i(\text{ref})} + 10 \text{ dB}$

**Notes**

1. The tests are executed without load on pins TPI and TPQ.
2. All minimum and maximum values correspond to a bit error rate (BER)  $\leq \frac{3}{100}$  in the wanted signal ( $P_1$ ).
3. The BER measurement is started 5 ms ( $t_{\text{on}(\text{max})}$ ) after  $V_{\text{RE}}$  goes HIGH; BER is then measured for 100 bits (BER  $\leq \frac{3}{100}$ ).

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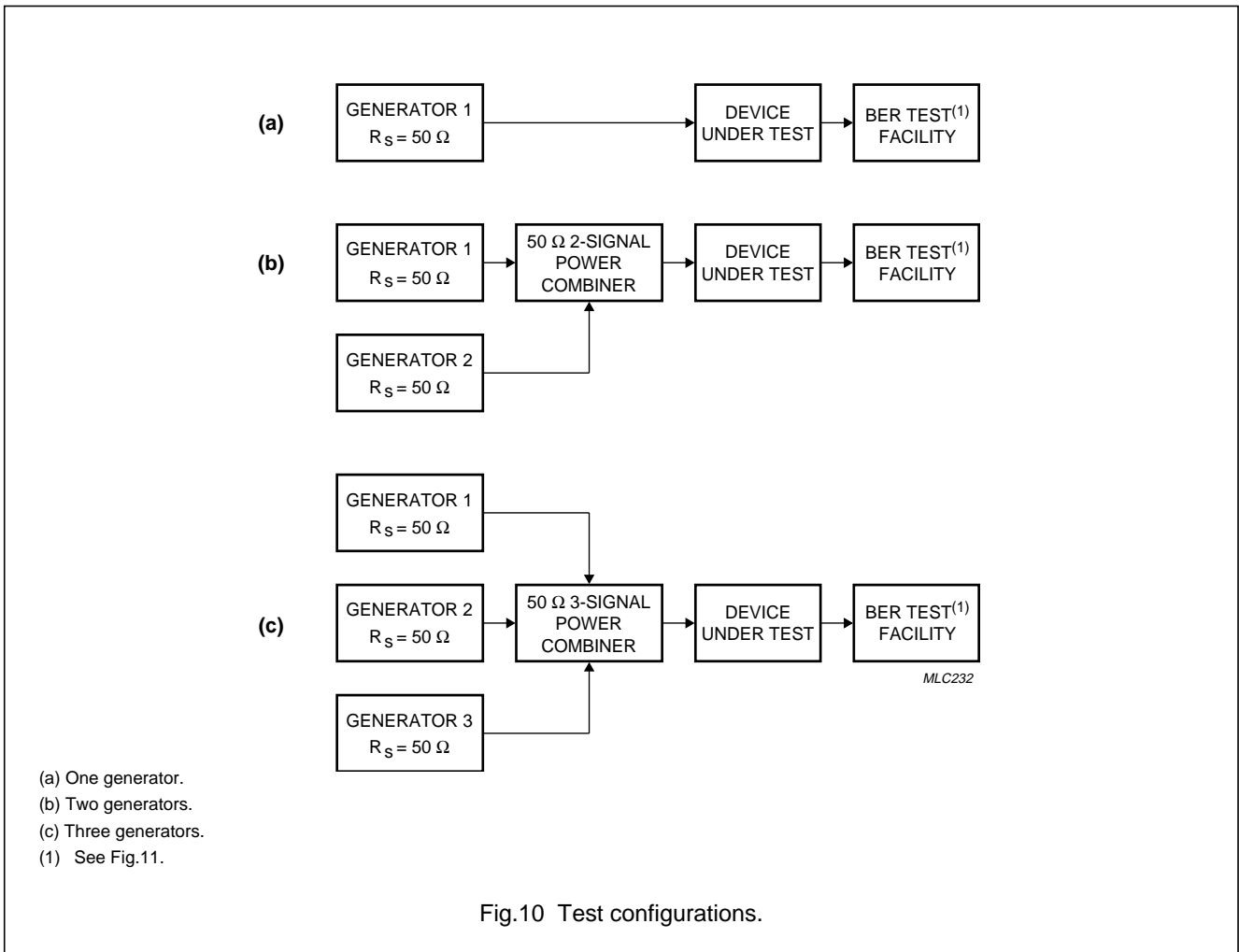


Fig.10 Test configurations.

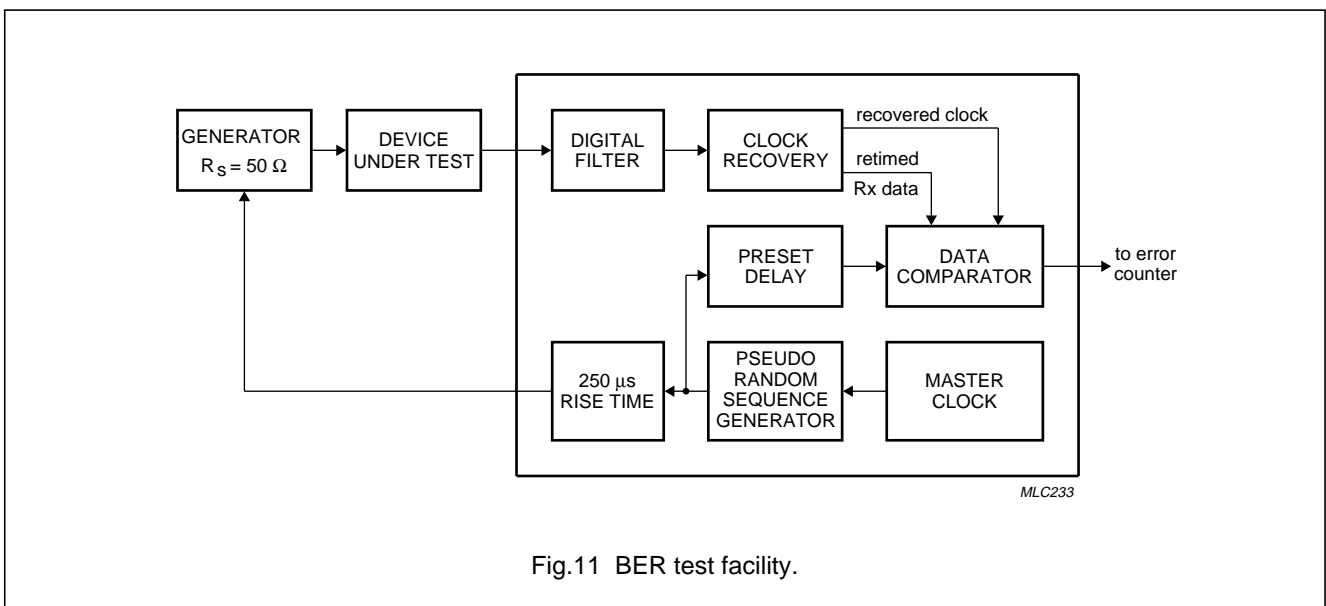
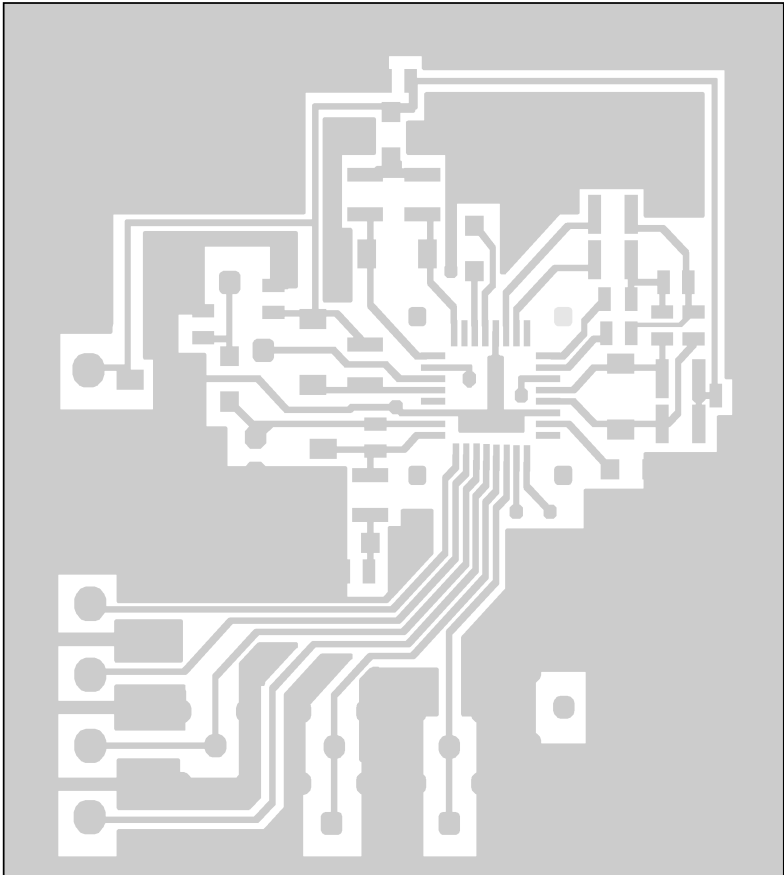


Fig.11 BER test facility.

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PRINTED-CIRCUIT BOARDS

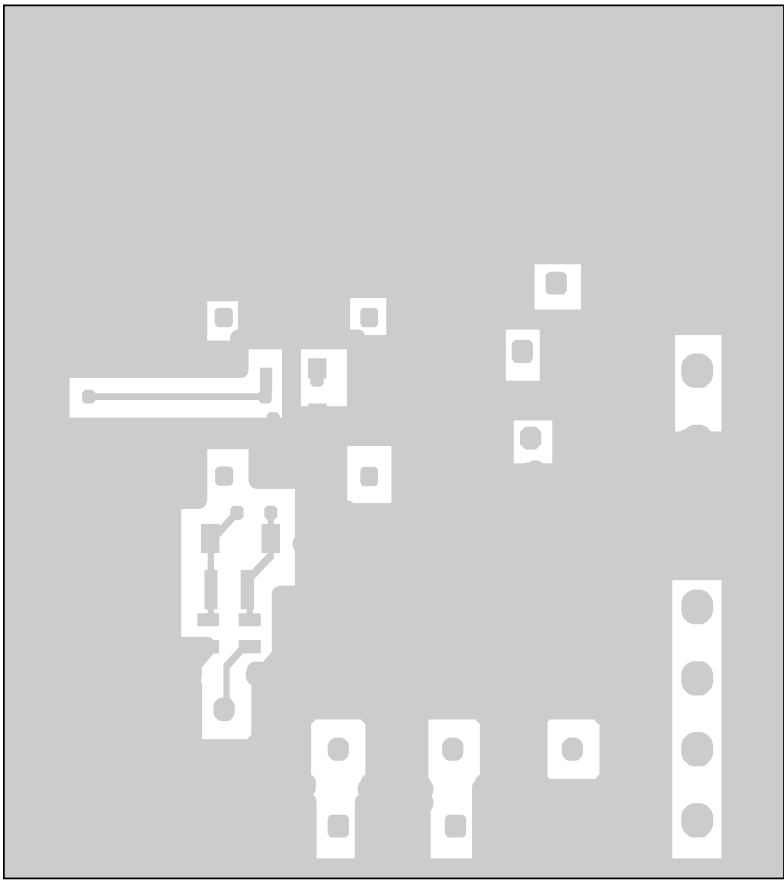


MBD562

Fig.12 PCB top view for LQFP32; test circuit Figs 1 and 3.

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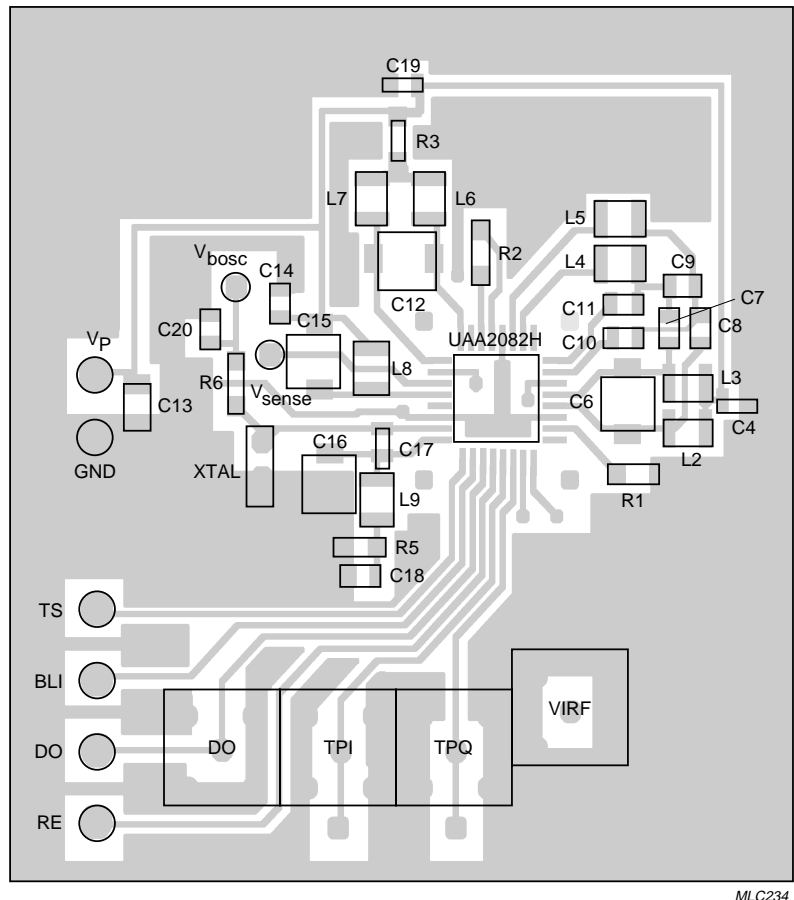
MBD561

Fig.13 PCB bottom view for LQFP32; test circuit Figs 1 and 3.



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$V_{EE} = GND; V_C = V_P.$

Fig.14 PCB top view with components for LQFP32; test circuit Fig.3.

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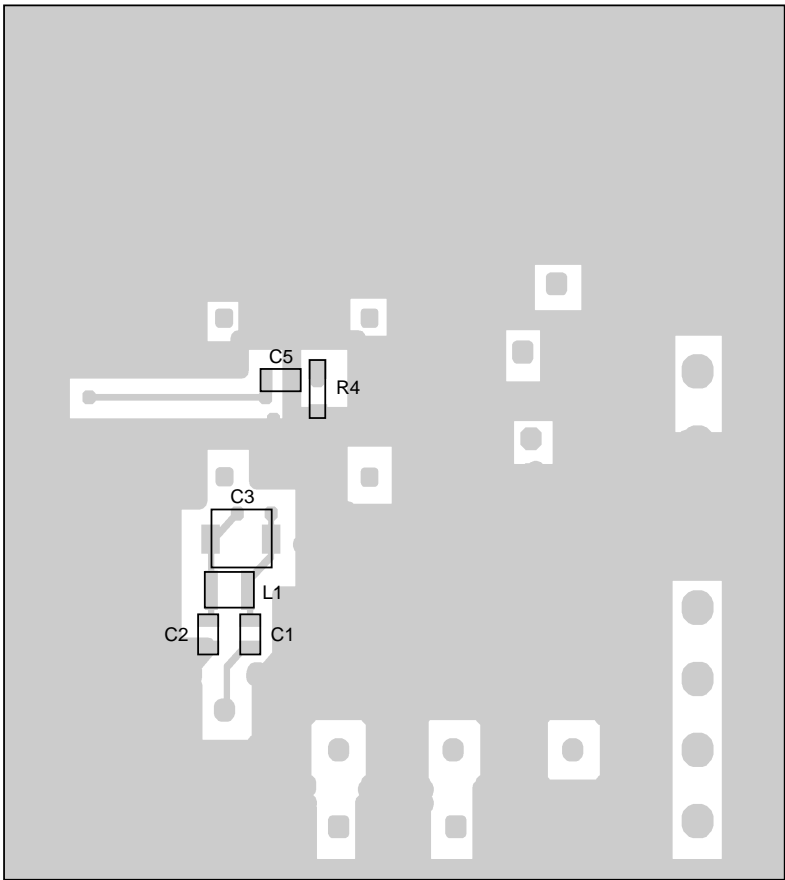


Fig.15 PCB bottom view with components for LQFP32; test circuit Fig.3.

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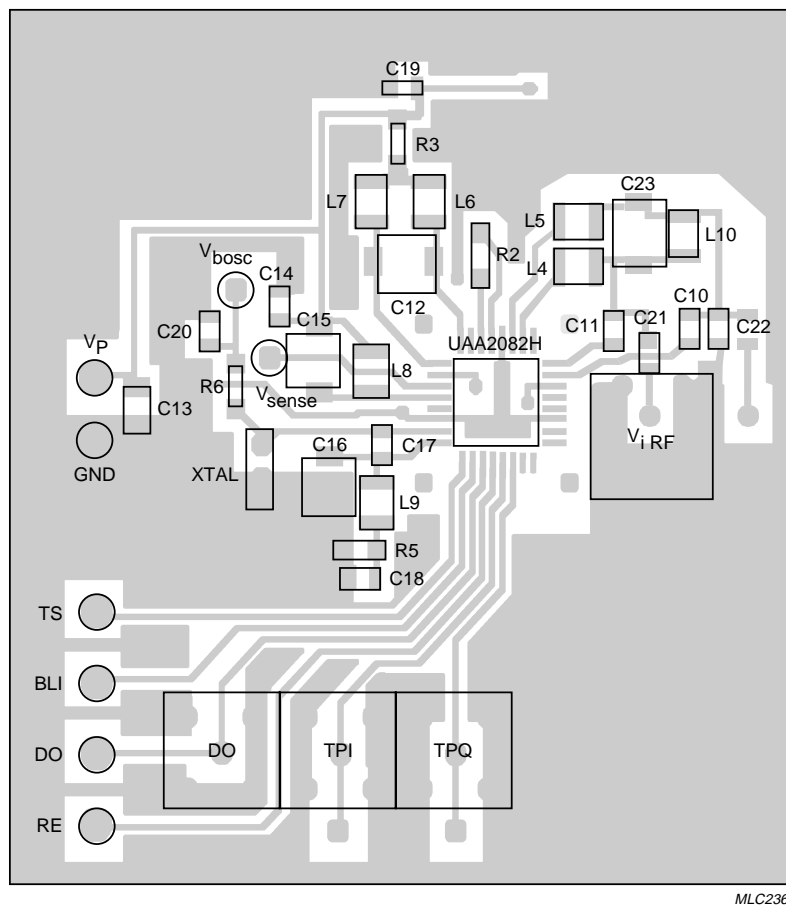
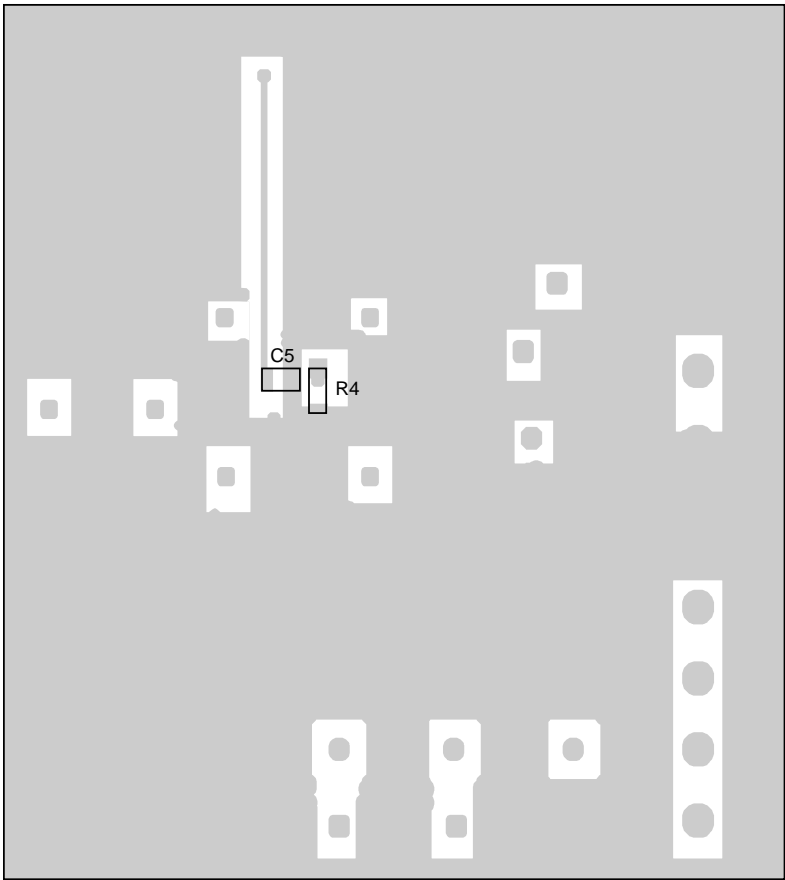


Fig.16 PCB top view with components for LQFP32; test circuit Fig.5.

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MLC237

Fig.17 PCB bottom view with components for LQFP32; test circuit Fig.5.

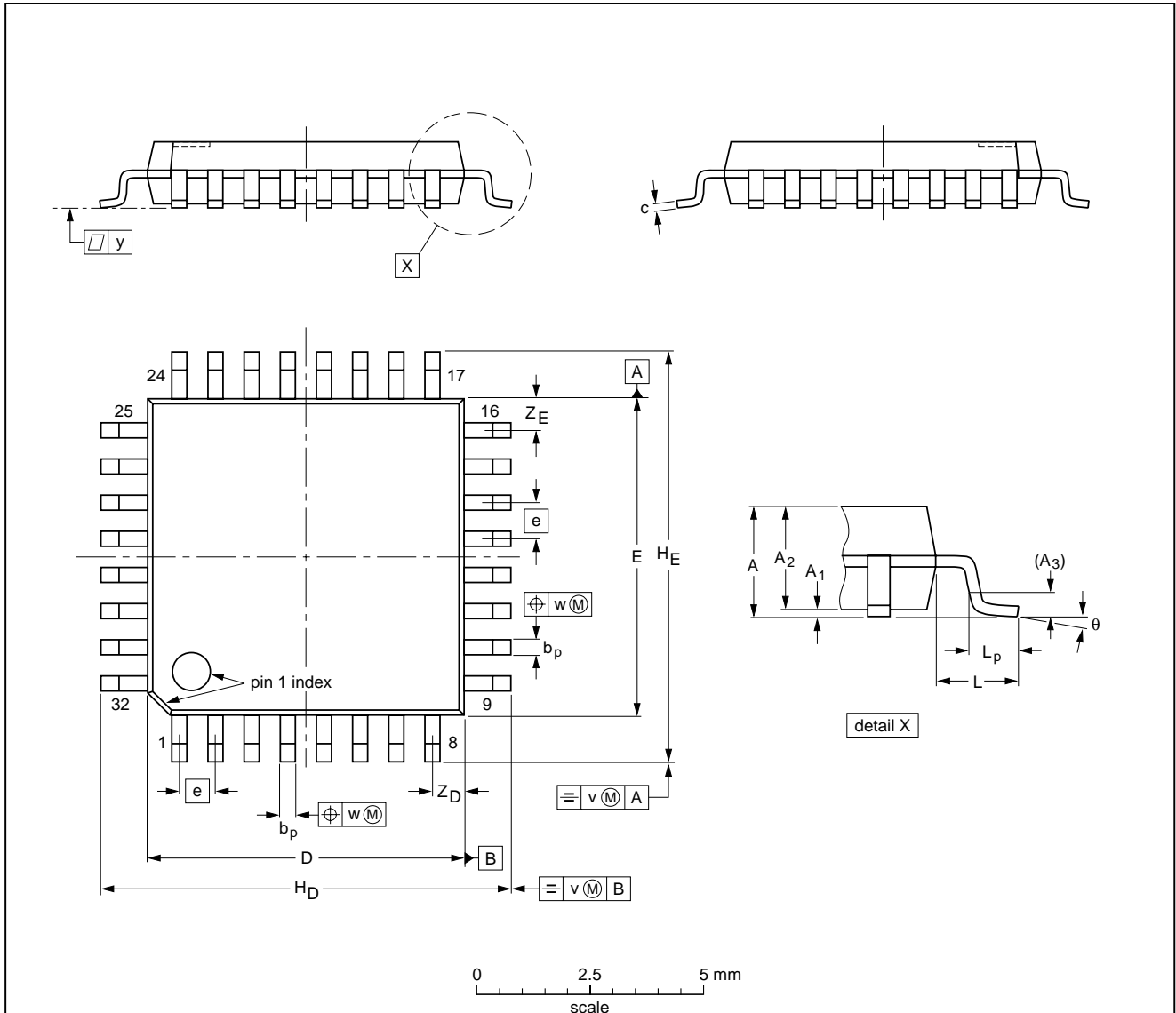
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PACKAGE OUTLINE

LQFP32: plastic low profile quad flat package; 32 leads; body 7 x 7 x 1.4 mm

SOT358-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>D</sub>	H <sub>E</sub>	L	L <sub>p</sub>	v	w	y	Z <sub>D</sub> <sup>(1)</sup>	Z <sub>E</sub> <sup>(1)</sup>	θ
mm	1.60	0.20 0.05	1.45 1.35	0.25	0.4 0.3	0.18 0.12	7.1 6.9	7.1 6.9	0.8	9.15 8.85	9.15 8.85	1.0	0.75 0.45	0.2	0.25	0.1	0.9 0.5	0.9 0.5	7° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT358 -1	136E03	MS-026				99-12-27-00-01-19

## Advanced pager receiver

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**SOLDERING****Introduction to soldering surface mount packages**

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

**Reflow soldering**

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

**Wave soldering**

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
  - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

**Manual soldering**

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
	WAVE	REFLOW <sup>(1)</sup>
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable <sup>(2)</sup>	suitable
PLCC <sup>(3)</sup> , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended <sup>(3)(4)</sup>	suitable
SSOP, TSSOP, VSO	not recommended <sup>(5)</sup>	suitable

Notes

1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the *“Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods”*.
2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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## DATA SHEET STATUS

DATA SHEET STATUS	PRODUCT STATUS	DEFINITIONS <sup>(1)</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

## Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

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